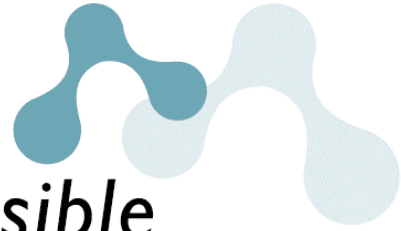
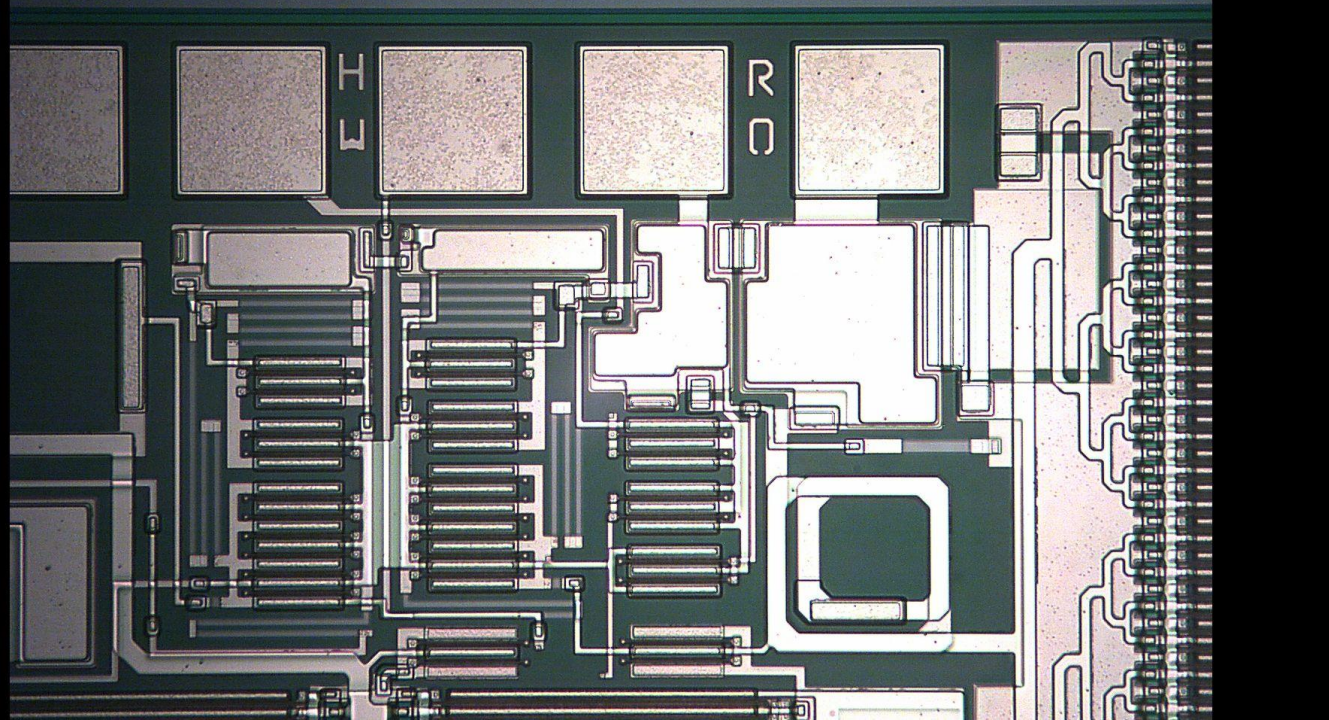
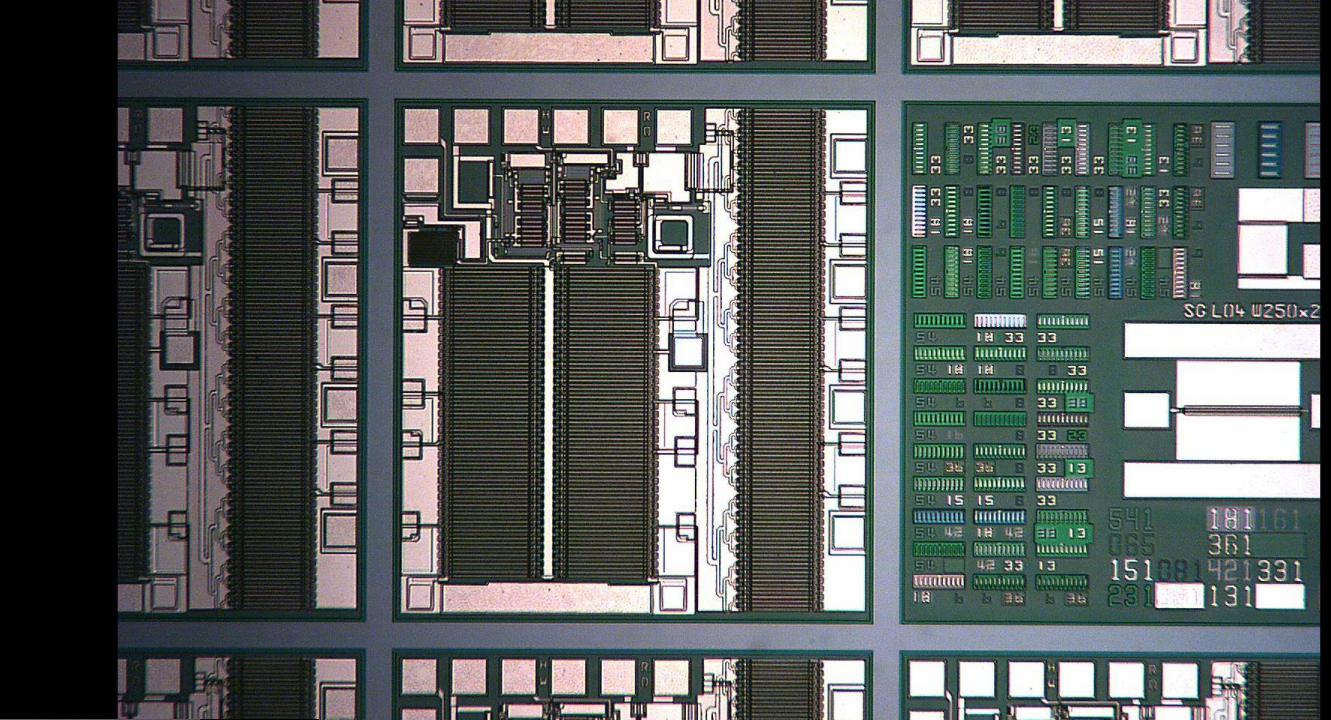


# ASAP



*as soon as possible*



**ASAP Co.,Ltd.**  
**Company information**

# Overview

<b>Name</b>	<b>ASAP Co.,Ltd.</b>
<b>Establish</b>	Feb 1999
<b>Location</b>	Head office : 27-1, Sanjo-machi, Nishi-ward, Saitama-city Okinawa factory : 5192-41, Katsuren-haebaru, Uruma-city
<b>Representative</b>	Makoto Osawa
<b>Capital</b>	40,000,000 JPY
<b>Shareholder</b>	NANYO Corp. 100%
<b>Business activities</b>	Production and marketing of semiconductor equipment Marketing of semiconductor materials Semiconductor production related consulting
<b>Products</b>	Equipment of lithography, scrubber etc

# Location

< Head Office >

27-1, Sanjo-machi, Nishi-ward,  
Saitama-City, SAITAMA



< Okinawa factory >  
5192-41, Katsurehaebaru,  
Uruma-City, OKINAWA  
(Special Economic Zone for trade )



# Main Products



Coater



Mask Aligner



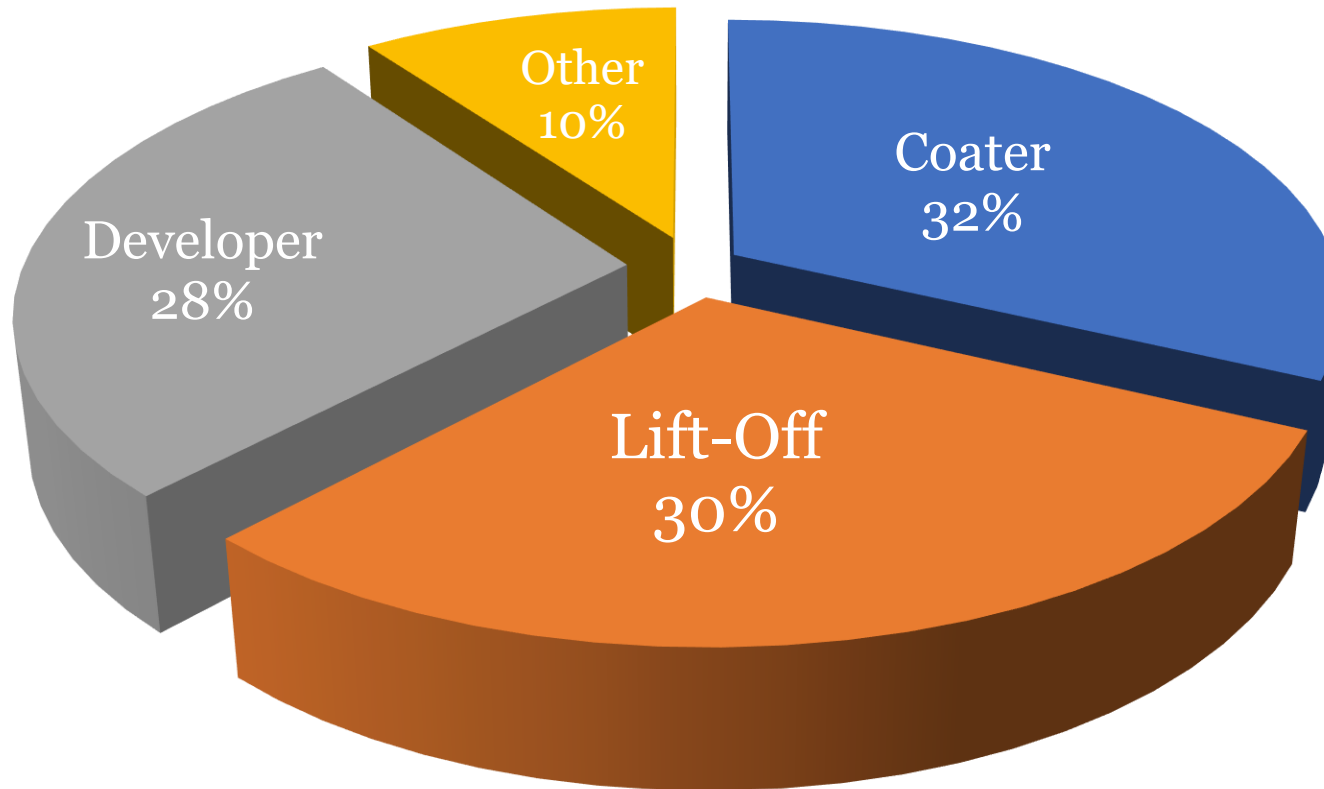
Developer



Lift-Off

# Delivery Record

## Products Shipped (up Dec 2023)



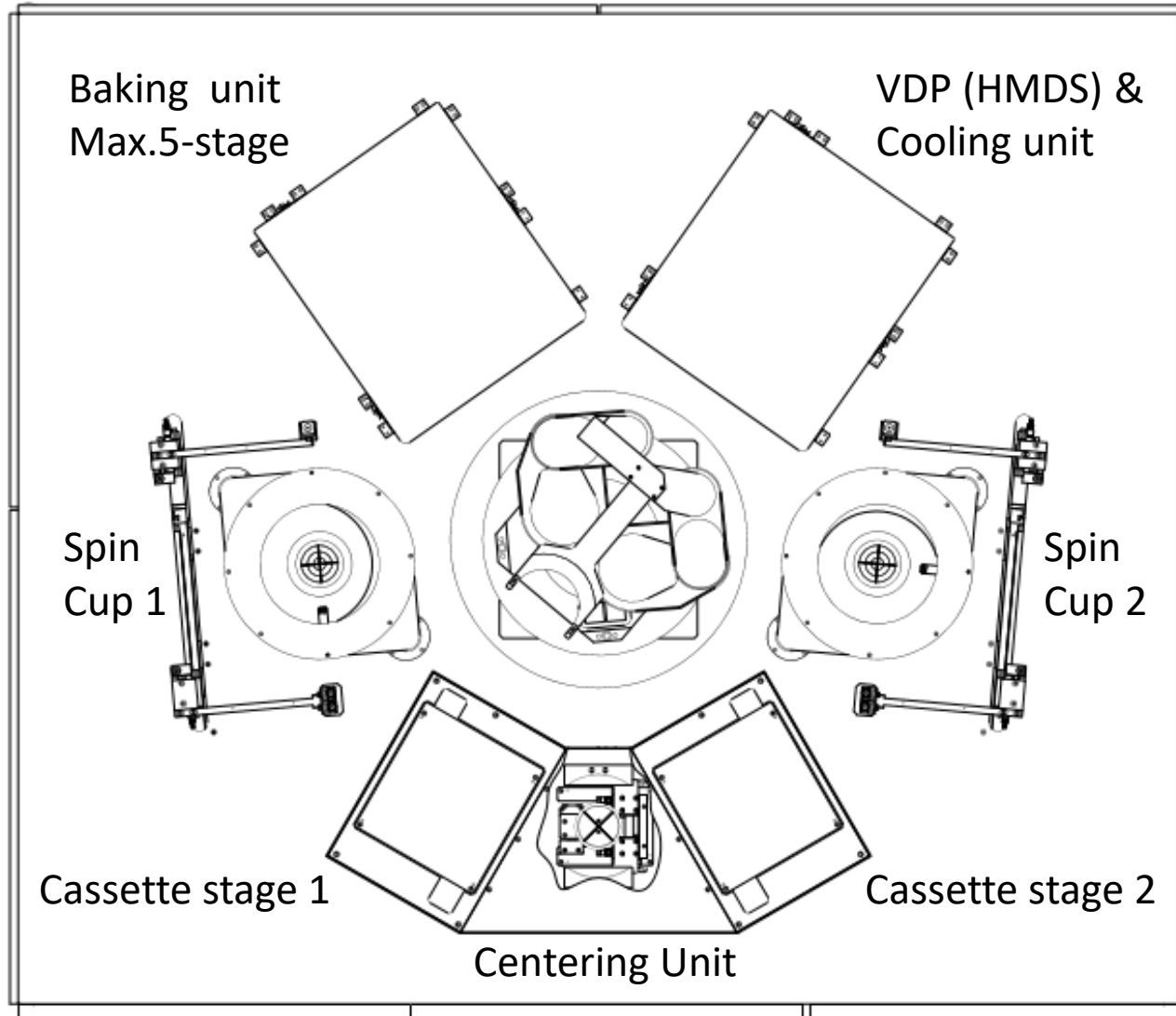
300+ Sets

### Basic Enclosure of:

- Stand alone Spin Coater
- Stand alone Spin Developer
- Combo Coater & Developer
- Metal Liftoff System
- Wafer Scrubber / Cleaner
- Mask Aligner

# **Spin Coater & (Developer)**

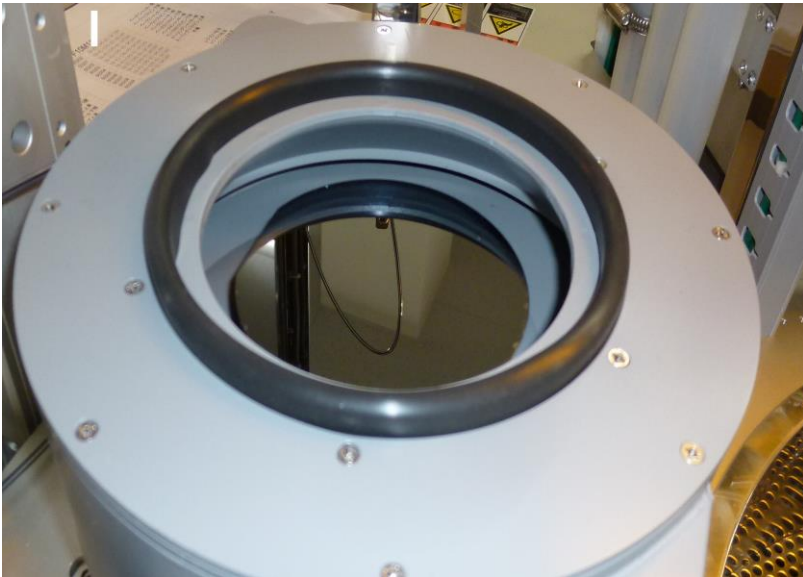
# Typical System Configuration



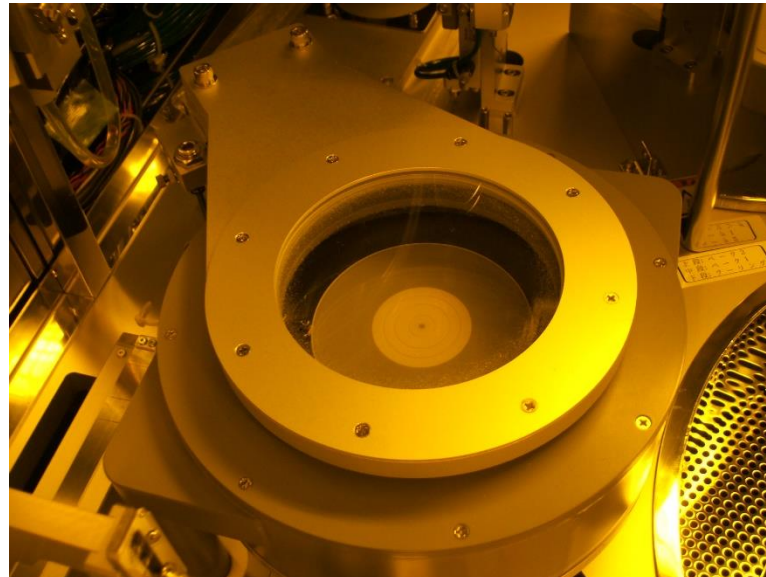
# Process Cup Design of Coating system

Cup design differs from depending on viscosity, substrate shape and target thickness.

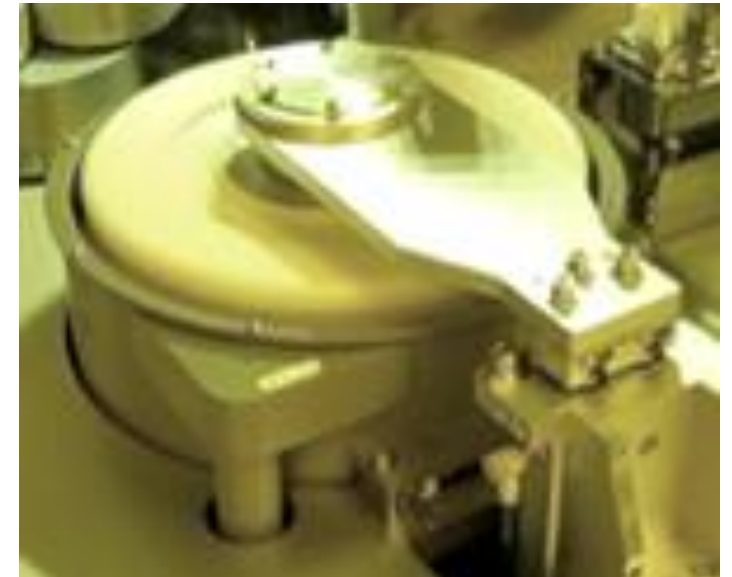
## OPEN



## CLOSE



## ROTATION



For thin film coating or  
Low Viscosity Photoresist,  
mainly for **Positive PR**

For thick film coating or  
High Viscosity Photoresist,  
Mainly for **Negative PR**

For **Square substrate** or  
Expecting good coverage,  
**Less material** coating (eg) **PI**



# High viscosity coating data

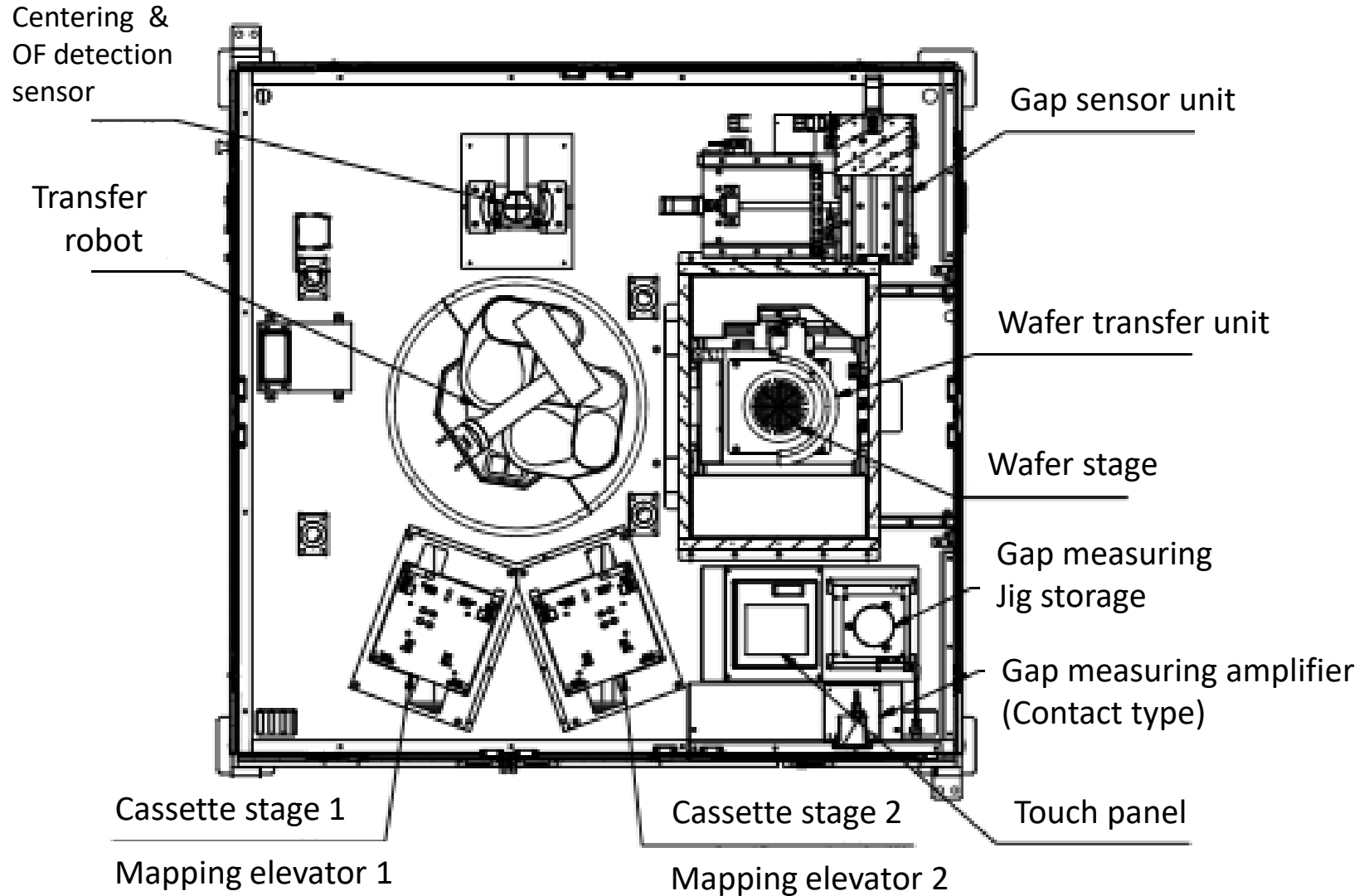
Photo Resist	Tokyo Ohka	AZ electronics	TOK	JSR	HD microsystems
Model	TCIR	AZ-4620	PMER-LA900	THB	PIX-3400
Viscosity	96 cp	400 cp	900 cp	1,750 cp	13,000 cp
Wafer size	8 inch	8 inch	8 inch	8 inch	6 inch
Thickness	40,000 Å	62,500 Å	300,000 Å	413,000 Å	100,000 Å
Uniformity (max-min)/ave	1.39 %	1.67 %	2.68 %	3.76 %	4.7 %
W to W uniformity	0.84 %	0.91 %	1.02 %	1.13 %	1.51%

# **Auto Mask Aligner**

## **Model: AMA6000**



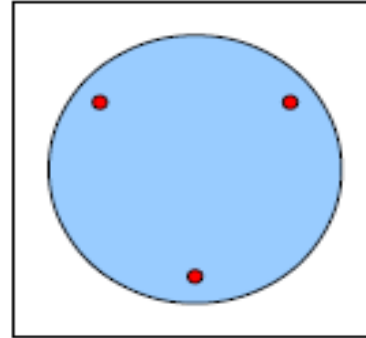
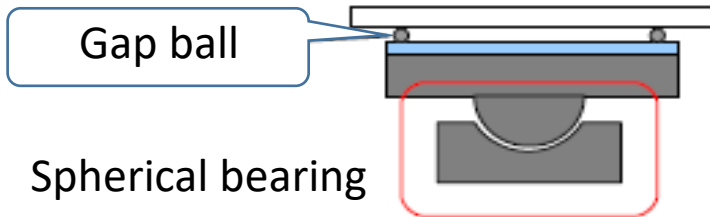
# System configuration & Dimension



Size : 1200 x 1260 x 2000 mm

# Features of ASAP Mask Aligner

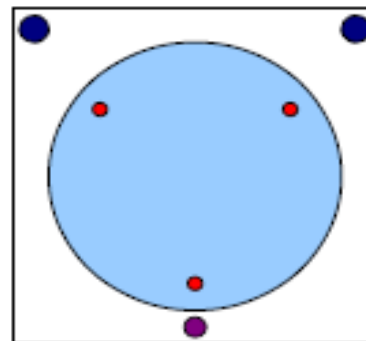
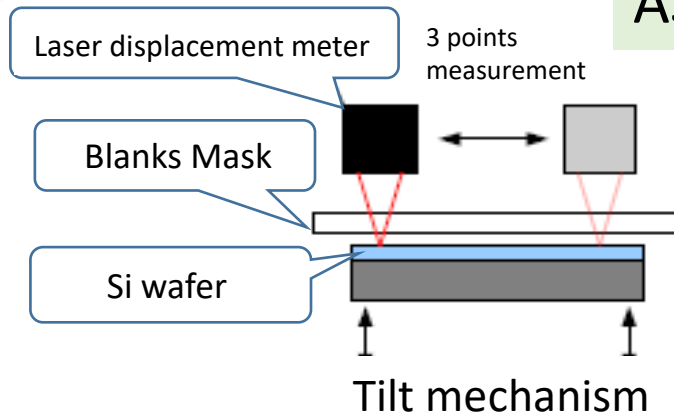
## Conventional method



- Gap ball contact point

Gap ball makes a damage to the mask.

## ASAP method

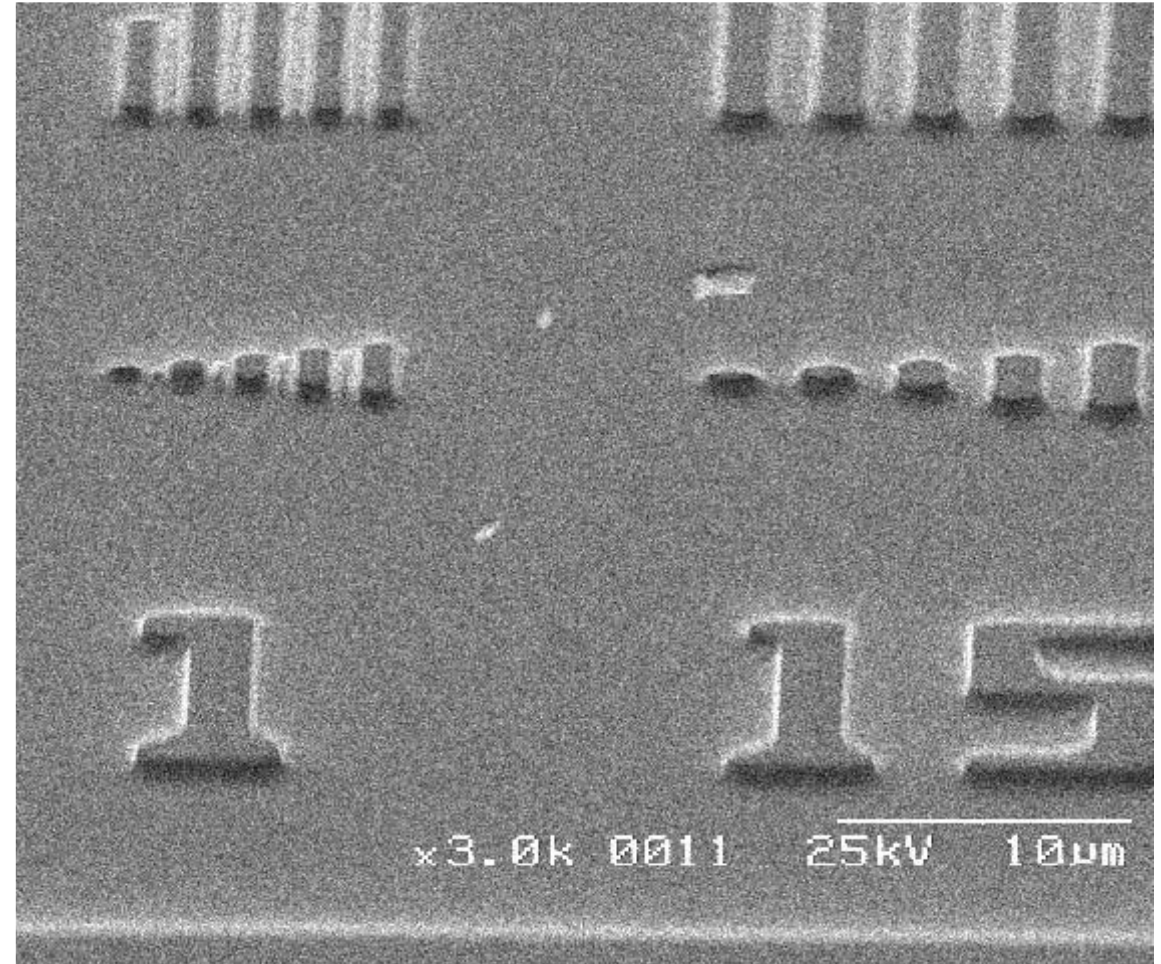


- : Tilt drive shaft
- : Tilt fixing shaft
- : Gap measuring point

No damage to the wafer & mask is realized by non-contact.

# Exposure Performance

【Conditions】		
Substrate	:	Si (OAP treatment )
Film Thickness	:	0.8um ( OFPR-800LB )
Prebake	:	90°C / 90s
Development	:	NMD-3 ( 2.38% )
Rinse	:	DI water / 20s



# **Metal Lift-Off System**

# Process method comparison (2)

Liftoff process needs **chemical effect** to dissolve photo-resist, and **physical force** to remove metal from substrate.

Process method	Strong point	Weak point
Dip + High pressure	<ul style="list-style-type: none"> <li>• High productivity</li> <li>• Easy to recycle chemical</li> <li>• Optimize the current Wet bench</li> </ul>	<ul style="list-style-type: none"> <li>• <b>Metal redeposit issue</b></li> <li>• Big footprint per WPH</li> <li>• High initial cost</li> </ul>
Tape + Dip	<ul style="list-style-type: none"> <li>• Low initial cost</li> <li>• Less chemical consumption</li> </ul>	<ul style="list-style-type: none"> <li>• <b>Burr issue</b></li> <li>• Need 2 step process ( not exist integrated equipment )</li> <li>• Low metal recycle rate</li> </ul>
Dip + Ultrasonic( or spray )	<ul style="list-style-type: none"> <li>• Lowest initial cost</li> <li>• Less chemical consumption</li> </ul>	<ul style="list-style-type: none"> <li>• <b>Burr issue</b></li> <li>• <b>Metal redeposit issue</b></li> <li>• Low metal recycle rate</li> </ul>
ASAP's high pressure system ( Fully single wafer process )	<ul style="list-style-type: none"> <li>• Highest productivity and repeatability</li> <li>• Lowest chemical consumption</li> <li>• <b>No redeposit, No burr, Better yield</b></li> </ul>	<ul style="list-style-type: none"> <li>• Moderate to high initial cost</li> <li>• Easily recovered yield improvement and chemical cost</li> </ul>

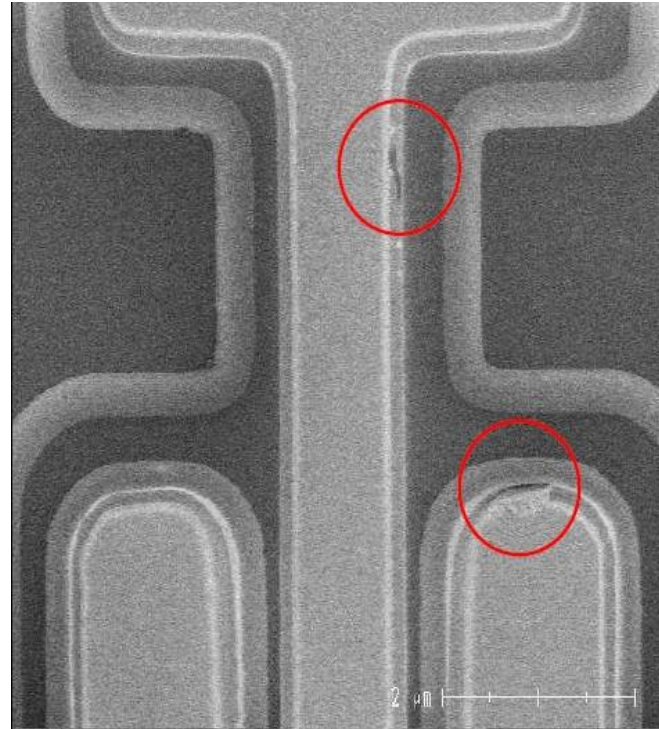
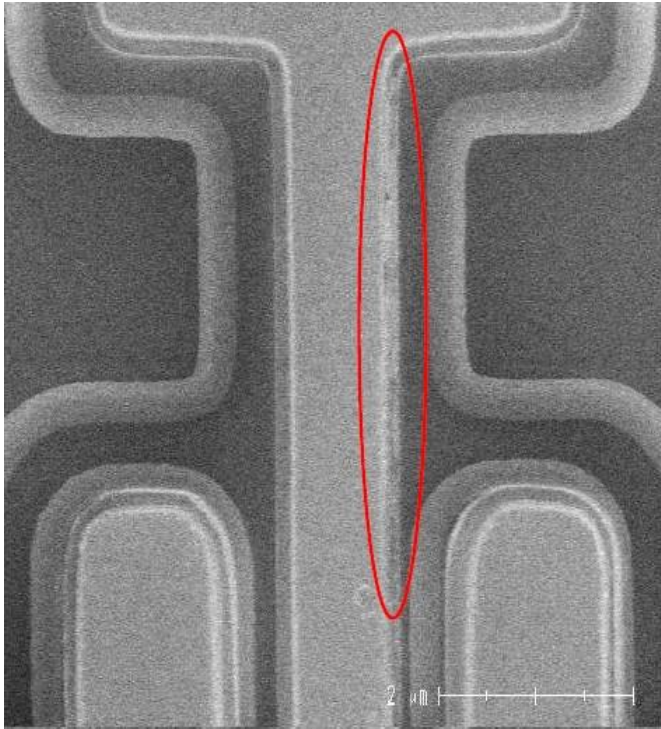
**ASAP's high pressure system** is much different from other supplier's.  
Our system occurs very powerful **Micro-Cavitation (MC)**.

MC makes micro-bubble in liquid (solvent)  
which has very strong detergency. It realizes  
**short time process, no burr, less chemical consumption, etc...**



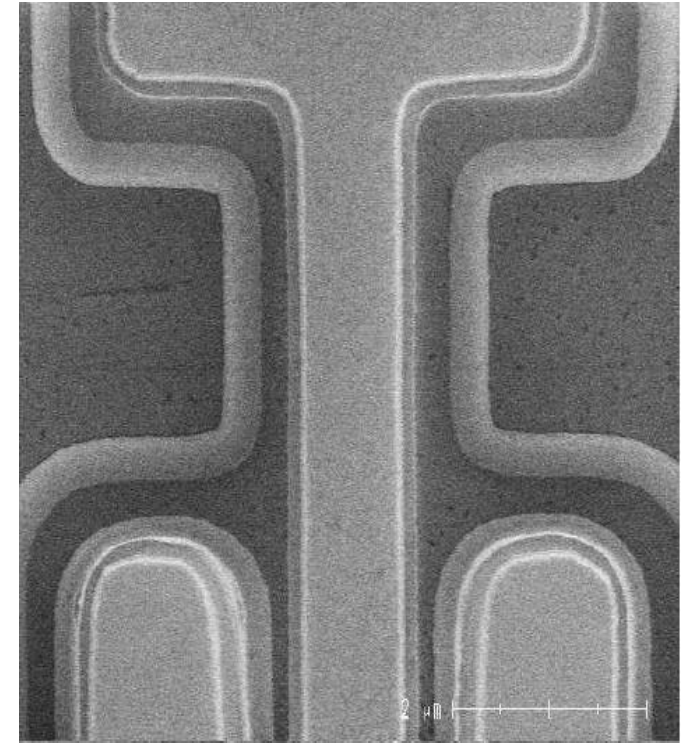
## < Example of burr issue improvement >

Dip + High pressure

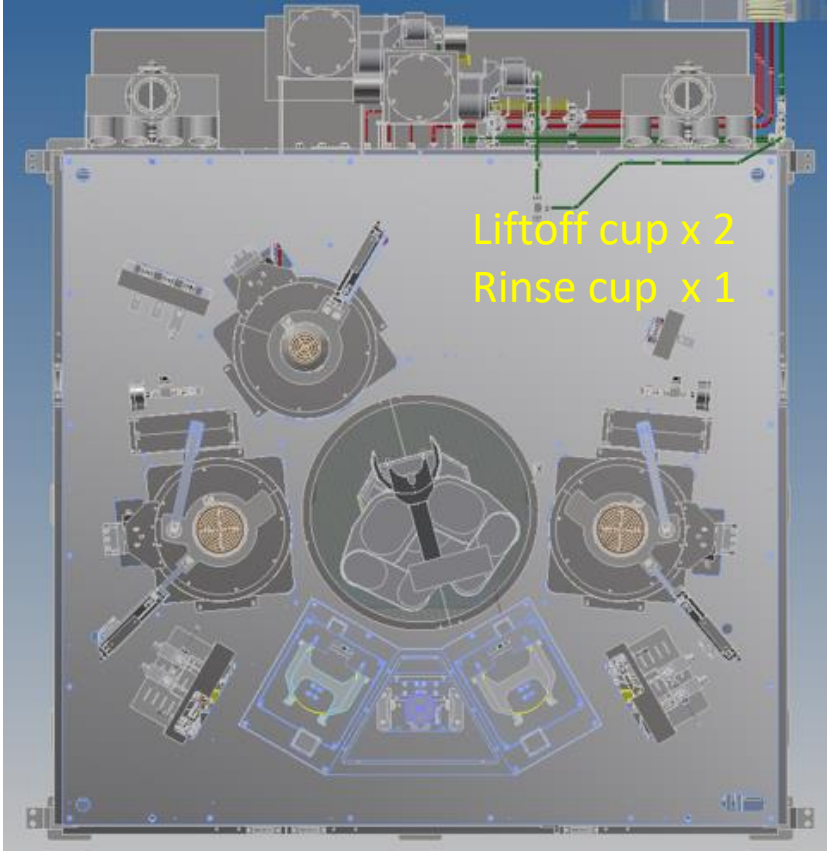


VS

ASAP's High pressure



# 3-CUP System Configuration (Max. $\phi$ 6 inch)



Main system dimension  
1600 x 1500 x 1900 mm

Chemical cabinet  
with recycle system

